



Shantou Huashan Electronic Devices Co.,Ltd.

NPN SILICON TRANSISTOR

**KSH13009**

## HIGH VOLTAGE SWITCH MODE APPLICATIONS

High Speed Switching

Suitable for Switching Regulator and Monitor Control

## ABSOLUTE MAXIMUM RATINGS ( $T_a=25^{\circ}\text{C}$ )

$T_{\text{stg}}$ —Storage Temperature.....  $-55\sim 150^{\circ}\text{C}$

$T_j$ —Junction Temperature.....  $150^{\circ}\text{C}$

$P_C$ —Collector Dissipation ( $T_c=25^{\circ}\text{C}$ ) ..... 100W

$V_{\text{CBO}}$ —Collector-Base Voltage..... 700V

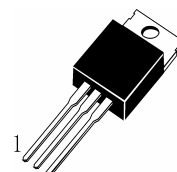
$V_{\text{CEO}}$ —Collector-Emitter Voltage..... 400V

$V_{\text{EBO}}$ —Emitter-Base Voltage..... 9V

$I_C$ —Collector Current (DC) ..... 12A

$I_B$ —Base Current.....6A

TO-220



1—Base, B

2—Collector, C

3—Emitter, E

## ELECTRICAL CHARACTERISTICS ( $T_a=25^{\circ}\text{C}$ )

| Symbol                | Characteristics                       | Min        | Typ        | Max        | Unit                            | Test Conditions                                                                                               |
|-----------------------|---------------------------------------|------------|------------|------------|---------------------------------|---------------------------------------------------------------------------------------------------------------|
| $V_{\text{CEO}}$      | Collector-Emitter Breakdown Voltage   | <b>400</b> |            |            | <b>V</b>                        | $I_C=10\text{mA}$ , $I_B=0$                                                                                   |
| $I_{\text{EBO}}$      | Emitter-Base Cut-off Current          |            |            | <b>1</b>   | <b>mA</b>                       | $V_{\text{EB}}=9\text{V}$ , $I_C=0$                                                                           |
| $H_{\text{FE}}$ (1)   | DC Current Gain                       | <b>8</b>   |            | <b>40</b>  |                                 | $V_{\text{CE}}=5\text{V}$ , $I_C=5\text{A}$                                                                   |
| $H_{\text{FE}}$ (2)   |                                       | <b>6</b>   |            | <b>30</b>  |                                 | $V_{\text{CE}}=5\text{V}$ , $I_C=8\text{A}$                                                                   |
| $V_{\text{CE(sat)1}}$ | Collector- Emitter Saturation Voltage |            |            | <b>1</b>   | <b>V</b>                        | $I_C=5\text{A}$ , $I_B=1\text{A}$                                                                             |
| $V_{\text{CE(sat)2}}$ |                                       |            |            | <b>1.5</b> | <b>V</b>                        | $I_C=8\text{A}$ , $I_B=1.6\text{A}$                                                                           |
| $V_{\text{CE(sat)3}}$ |                                       |            |            | <b>3</b>   | <b>V</b>                        | $I_C=12\text{A}$ , $I_B=3\text{A}$                                                                            |
| $V_{\text{BE(sat)1}}$ | Base-Emitter Saturation Voltage       |            |            | <b>1.2</b> | <b>V</b>                        | $I_C=5\text{A}$ , $I_B=1\text{A}$                                                                             |
| $V_{\text{BE(sat)2}}$ |                                       |            |            | <b>1.6</b> | <b>V</b>                        | $I_C=8\text{A}$ , $I_B=1.6\text{A}$                                                                           |
| $C_{\text{ob}}$       | Output Capacitance                    |            | <b>180</b> |            | <b>pF</b>                       | $V_{\text{CB}}=10\text{V}$ , $f=0.1\text{MHz}$                                                                |
| $f_r$                 | Current Gain-Bandwidth Product        | <b>4</b>   |            |            | <b>MHz</b>                      | $V_{\text{CE}}=10\text{V}$ , $I_C=0.5\text{A}$                                                                |
| $t_{\text{ON}}$       | Turn On Time                          |            |            | <b>1.1</b> | <b><math>\mu\text{s}</math></b> | $V_{\text{CC}}=125\text{V}$ , $I_C=8\text{A}$ ,<br>$I_{\text{B1}}=1.6\text{A}$ , $I_{\text{B2}}=-1.6\text{A}$ |
| $t_{\text{STG}}$      | Storage Time                          |            |            | <b>3</b>   | <b><math>\mu\text{s}</math></b> |                                                                                                               |
| $t_{\text{F}}$        | Fall Time                             |            |            | <b>0.7</b> | <b><math>\mu\text{s}</math></b> |                                                                                                               |